

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,890,835 B1
DATED : May 10, 2005
INVENTOR(S) : Jack Oon Chu et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,
Item [57], **ABSTRACT**,
Line 13, "contact for the SiGe/Si" should read -- contact of the SiGe/Si --.

Signed and Sealed this

Eleventh Day of October, 2005



JON W. DUDAS
Director of the United States Patent and Trademark Office